

KCE

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KCE Technical Information

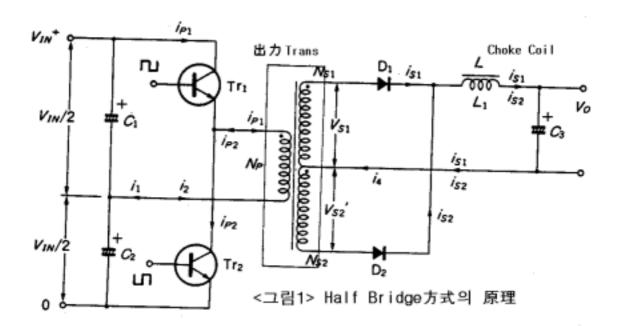
Half Bridge SMPS	Transformer	Vol:15
2004.2.6		

Half Bridge Push Pull

100V 200V

Push-Pull

1.



< 1> Half Bridge Vin 2 Capacitor C₁,C₂ Vin/2가 가 . C₁,C₂ Trans 1 Np . 2 Transister Tr₁,Tr₂ ON/OFF Tr_1 Base 가 가 Tr_1 ON 1 i_{p1} Trans Np Np 가 Vin/2 2 N_{s1} $V_{s1} = \frac{N_{s1}}{N_n} \bullet \frac{V_{IN}}{2}$. N_{s2} V_{s2} V_{s1} . V_{s1} 2 Diode i₅₁가 平滑Coil L Capacitor C₃ D₁ 2 Tr₁ OFF Tr₂가 ON Trans Diode Capacitor C₃ D₂가 i_{s2}가 平滑 Coil L

.1 2

가

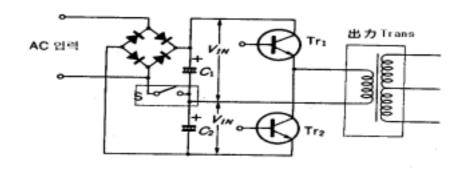
 V_{o}

$$V_0 = \frac{t_{ON}}{\left(T/2\right)} \bullet \frac{N_s}{N_p} \bullet \frac{V_{IN}}{2} = \frac{t_{ON}}{T} \bullet \frac{N_s}{N_p} \bullet V_{IN}$$

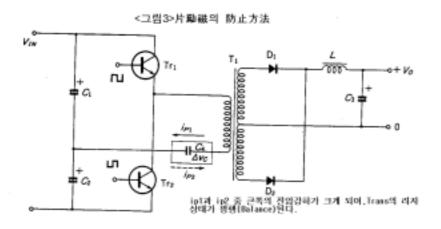
2.100V /200V

Capacitor C ₁ ,C ₂				Trans ′	1	Np	TR	ON	$V_{iN}/2$
가	OFF		TR	$V_{\text{CE}} = V_{\text{IN}}$	가				
Push-Pull			TR					2	
Capacitor			<	2>	100\	/			가
Tr	$V_{\text{CE}} = 2V_{\text{IN}}$	가	. 200V		В	idge	가		가
	V_{CEO} 400 V	TR		100V /200V					

<그림2>Half Bridge方式의 入力整流回路



TR Np $V_{\scriptscriptstyle \mathsf{IN}}$ Push-Pull Trans Push-Pull 3.Capacitor Trans (偏勵磁) Half Bridge 2 Τr Trans < 3> Capacitor C₄ Capacitor C₄ 1> .< TR ON $t_{\sf stg}$



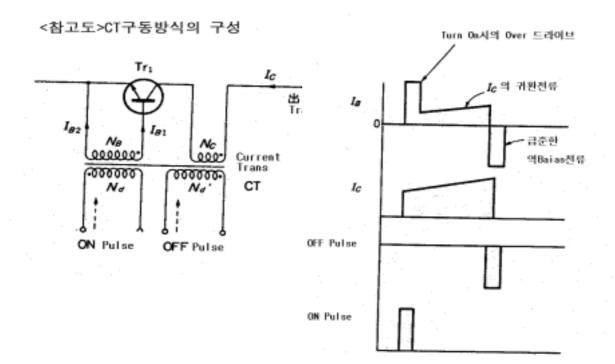


```
t<sub>stg</sub>가
                     TR ON
                                                    Capacitor
  Capacitor
                           Np
                                                    Trans
                                                                                       가
                                                              Capacitor
                                                             가
                            Capacitor
                                                                                Film
  Capacitor
4.Half Bridge
                          (Drive
  SMPS
              Switching TR
              (Forward
                                                    2
                                                          TR
                                                                      ON/OFF
                       가 .
                   Trans
                  ,2Trans ,CT(Current Transformer)
   1Trans
          CT
         < 4>,< 5>가 1Trans
                                         ,2Trans
         <그림4>1 Trans에 의한 驅動回路
                                                    <그림5>2 Trans에 의한 驅動回路
                           出力 Trans
                                                                        구동Trans를 Tr1.Tr2 각각 별
                            Tr3가 ON하여 Tr1이 ON하지
                                                                        도로 하면 삼호의 간섭이 없기
                                                駆動 Trans
                            만 OFF할때에 역Baias를 인
                                                                        때문에 자유롭게 역 Briss를
  駆動 Trans
                                                                        개발 수 있다.
                            가하면 Tr1의 OFF와 동시에
            00000-00000-
                            Tr2가 ON에 버린다.이 때문
                             에 Tr1과 Tr2의 역 Baias가
                             걸리지 않는다.
            가 TR
                                       MOS-FET
                                                                             TR
  СТ
                    СТ
       Page
5.Half Bridge
                Regulator
          :AC85~115V
             117~230V
          :+36V,5A
            :25KHz
```

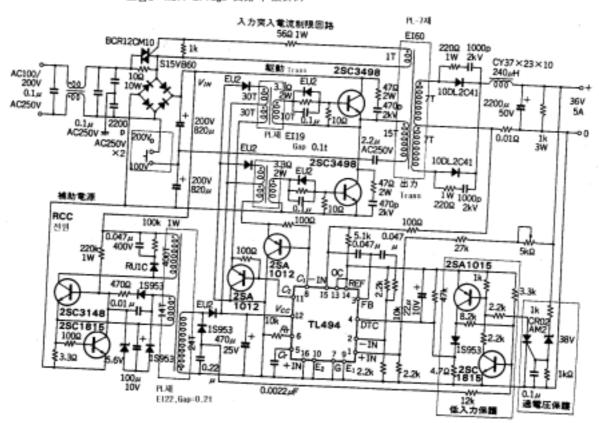
6>

Regulator <

Half Bridge







```
6.
  5.Half Bridge Regulator
(1) Trans .(SMPS Transformer
                                                            )
   1
               100V
                                                                                V_{IN(max)}
                                                                                           Trans 1
                                                        1
          Np .Trans Core Samwha
                                                    PL-7 EI60
          N_{P} = \frac{V_{IN(\text{max})} \bullet t_{ON(\text{max})} \bullet 10^{8}}{2 \bullet \Delta B \bullet A_{\rho}}  (1)
          t_{ON} = T/2 (1)
          N_{P} = \frac{V_{IN \text{ (m ax)}} \times 10^{8}}{4 \bullet \Delta B \bullet A_{a} \bullet f} \qquad (2)
          . t_{oN}=T/2 ON
                                                                                 가
                                                                                           ON
                   Dead Time
                                                      (2)
                                                                                 (1)
               가 (2)
                                                                   . Core 가
   Core
                            (1)
   Dead Time
                                                  가
                                                                               가
                Soft Start
           N_{P} = \frac{V_{IN(\text{max})} \bullet t_{ON(\text{max})} \times 10^{8}}{B \bullet A_{I}} \qquad (3)
                                가 가 Trans가
                              A_e:Core (cm<sup>2</sup>)
                               B:
                                              (Gauss)
                              f :
                                         (Hz)
                             V_{\text{IN(max)}}: (Volt) B_m:Core \pm 2000 (4000 Gauss) \pm 2200 (4400 Gauss)
              B Bridge
                  (2)
        N_{P} = \frac{2 \times 115 \times \sqrt{2} \times 0.9 \times 0.5 \times 10^{8}}{4 \times 4000 \times 2.47 \times 25 \times 10^{3}} = 14.8T_{S} (4)
     가 . 0.5 V_{IN}/2가 가
    2
                            Duty Cycle D_{max} Tr Daed Time(t_d)
    2
             D_{\max} = \frac{(T/2) - t_d}{(T/2)} \qquad (4)
```

.Dead Time 3uS

D_{max} 0.85가

Diode V_F,Line Drop

 V_{LD} V_{S}

$$V_{_S} = \frac{V_{_0} + (V_{_F} + V_{_{LD}})}{D_{_{max}}} = \frac{36 + (1 + 0.5)}{0.85} = 44.1(V) \text{ 7}$$
 . $N_{_S}$

$$N_{S} = \frac{V_{S}}{V_{IN(min)}} \bullet N_{P} \qquad (5)$$

가 .

$$N_s = \frac{44.1}{2 \times 85 \times \sqrt{2} \times 0.9 \times 0.5} \times 15 = 6.1T_s$$

1,2 Peak

Diode

Choke Coil

 $\begin{array}{cccc} Diode & & i_{\mbox{\tiny SP}} & 20\% \\ Ripple & i_{\mbox{\tiny L}} & & 30\%_{\mbox{\tiny P-P}} & 7 \\ \end{array}$

$$i_{SP} = 1.2 \times (I_0 + \frac{\Delta i_L}{2}) = 1.2 \times (5 + \frac{1.5}{2}) = 6.9 A$$
 7}

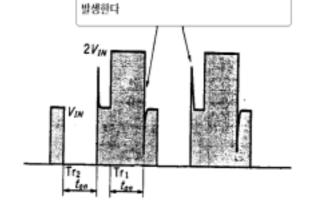
$$i_{1P} = \frac{N_s}{N_P} \bullet i_{SP} = \frac{7}{14} \times 6.9 = 3.45(A) \text{ 7}$$
.

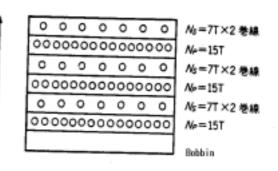
Trans의 Leakage L에 의해 서지전압이

<그림7>Half Bridge의 電壓波形

<그림9>권선 방법의 예

결합도를 올리기 위하여 Bobbin의 밑에서 부터 Np.Ns를 가 능한 회수를 많이 샌드위치 권선하여 결선시 각각 병렬 접속 한다(3회의 예)





Trans 1 2

Leakage Inductance가 가 < 7>

TR

OFF

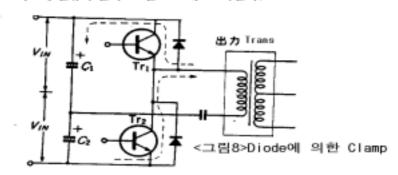
TR

8>

Sandwich

Diode

Trans Leakage Inductance 반대측 Tr이 OFF하였을때 서지 전압으로 Vce>2Vin이 되면 Diede를 통하여 C1,C2에 진류가 흘러 Vce를 2Vin에 Clamp한다.



2) Choke Coil

> 2 OFF Forward

Inductance

 $V_{\text{S}(\text{max})}$

$$V_{s(max)} = \frac{N_P}{N_S} \bullet V_{IN(max)} = \frac{7}{14} \times 2 \times 115 \times \sqrt{2} \times 0.9 \times 0.5 = 73.2(V)$$

가

Duty Cycle D_(min)

$$D_{(min)} = \frac{V_0}{V_S - (V_E + V_{LD})} = \frac{36}{73.2 - (1 + 0.5)} = 0.5$$
 ON $t_{ON} = 10us$

가

Ripple i_L $30\%_{P-P}$ 가 Inductance LChoke Coil

 $\Delta i_L = 0.3 \times I_0 = 1.5(A)$

$$L = \frac{V_L}{\Delta i_L} \bullet t_{on} = \frac{V_s - (V_0 + V_F + V_{LD})}{\Delta i_L} \bullet t_{ON} = \frac{73.2 - (36 + 1 + 0.5)}{1.5} \times 10 \times 10^{-6} = 238(\text{uH})$$

< 2> .

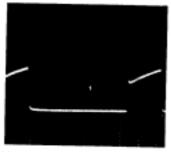
3) Trans

> RCC .RCC Transformer

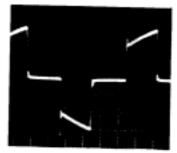
"SMPS Transformer"



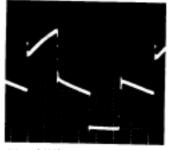
(a) Vcε被形(50 V/div, 5 μs/div)



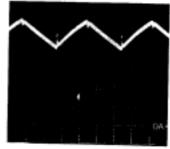
(b) Callecter 電流(2 A/div, 5 µs/div)



(c) Trans 1次卷線電流波形 (I A/div, 5 µs/div)



(d) 2次整流 Binde의 電流激形 (1 A/div. 5 µs/div)



(e) Choke Coil의 電路級形 (I A/div. 5 µs/div)

<사진2>各部의 波形

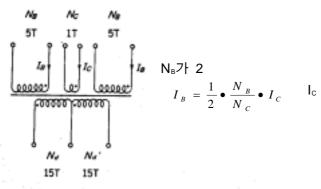
4.CT Trans <

11>CT Base

Base

Collecter

<그림11>CT의 Base電流



 N_c , N_B

 h_{FE}

$$N_c$$
 1Ts $h_{FE}=10$

$$I_B = \frac{1}{2} \bullet \frac{N_B}{N_C} \bullet I_C$$

$$I_B = \frac{N_B \bullet I_C}{2 \bullet N_C}$$

$$\frac{N_C}{N_B} = \frac{1}{2} \bullet \frac{I_C}{I_B} = \frac{1}{2} \bullet h_{FE}$$

가 . h_{FE} 가 10 5가 . h_{FE} 가 20 Baias

10

 $V_{\scriptscriptstyle BE}$

$$N_d = \frac{V_{CC}}{V_{BE}} \bullet N_B = \frac{15}{5} \times 5 = 15T_S$$

 V_{cc} =15V, Baias V_{BE} =5V .

TL494 IC . EI16(EE1625),EI19(EI1925) Core 가 .

Core

 $N_d = N_{d}: N_B: N_C = 30_{TS}: 10_{TS}: 1_{TS}$

Trans Trans Core Air Gap .